

# Proximity and vortex pinning in YBCO/LSMO bilayers

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Phys. Dept. NTHU. 2005/10/4



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# Outline

I. Introduction

High-Tc Superconductor Colossal magnetoresistive manganite Proximity and vortex pinning

- II. Experiment
- III. Results & discussion

IV. Conclusion

**Zero resistance in YBCO** 





M.K. Wu & C.W..Chu, PRL 58 (1987)





T < Tc



## Vortex structure in type II superconductor





## Vortex pining in type II superconductor





## BCS Theory Work?

 $k_B T_c \sim h\omega \exp[-1/g]$ g = N(0)V





Phonon-electron interaction

Cooper pair



**BCS-like**  $k_B T_c = E_{char} \exp[-(1 + \lambda)/\lambda]$ 

**RVB**  $k_B T_c = C \delta (t_{\perp}^2/t_{\parallel}^2) U$  (Anderson, 1987)

**Hubbard model** 

$$k_{\rm B}T_{\rm c} = t_{\parallel} \, \delta \exp(-U \, \delta \,/\, t_{\parallel})$$
 (Cyrot, 1987)

**Charge-transfer/hole-depletion** 

$$T_c = T_{co} - A(n' - n_o)^2$$
 (Liechtenstein, 1995)

BCS + d<sub>x2-y2</sub> symmetry

$$\Gamma_{c} = [n_{H}(P), V_{eff}(P)]$$
 (Chen et al., 2000)

## **Colossal magnetoresistance (CMR)**





S. Jin et al. Science 265 (1994)

Very high magnetoresistance
(-1500% at 200 K)
Polarization 100% (half metal)
Metal - Insulator (PM -FM)
transition



## **Double exchange (1951, Zener)** (La,Sr,)MnO<sub>3</sub> eg eg **h**+ e $t_{2g}$ $\mathbf{t}_{2\mathbf{g}}$ $\mathbf{O}^{-2}$ SP Mn<sup>+3</sup>: 3d<sup>4</sup> ( $t_{2g}^{3} e_{g}^{-1}$ ) Mn<sup>+4</sup>: $3d^3(t_{2g}^3 e_g^0)$

Physical Review B, Volume 58, Number 17

Phase diagram of manganese oxide

**Ryo Maezono, Surnio Ishihara, and Naoto Nagaosa** Department of Applied Physics, University of Tokyo, Bunkyo-ku, Tokyo 113, Japan

 $H = H_K + H_{Hund} + H_{on site} + H_S$ 

$$H_{\kappa} = \sum_{\sigma\gamma\gamma'(ij)} t_{ij}^{\gamma\gamma'} d_{i\sigma\gamma'} d_{j\sigma\gamma'}$$
(Kinetic energy of e<sub>g</sub> electrons)

 $H_{Hund} = -J_H \sum_{i} \vec{S}_{t_{2g}i} \cdot \vec{S}_{egi} \quad \text{(Hund coupling between } e_g \& t_{2g} \text{ spins})$  $H_{\text{on site}} = -\sum_{i} (\vec{\beta} T_i^2 + \vec{\alpha} S_{egi}^2) \quad \text{(Coulomb interaction between } e_g \text{-electrons})$ 

$$H_{S} = J_{S} \sum_{(ij)} \overrightarrow{S}_{t_{2}gi} \cdot \overrightarrow{S}_{t_{2}gj} \qquad \text{(Super exchange } t_{2g} \text{ spins)}$$





#### **CMR effect toward to spintronic applications**

Туре	MR	Field	Temp.	Material
OMR	0.01%	~Tesla	RT	Cu,Al
AMR	2 %	10 Oe	RT	Fe,Co,Ni
GMR	5~10 %	2 Oe	RT	Fe/Cr
TMR	20 %	10 Oe	RT	Co/AlO/Co
CMR	10 (99.9)%	δ 2 T	RT(200K)	La-Sr-Mn-O





#### La<sub>0.7</sub>Sr<sub>0.3</sub>MnO<sub>3</sub>

YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub>

## **Interesting physics in SC/FM**





Boundary conditions  $\rightarrow$ 

- 1) Proximity effects
- 2) Magnetic vortex pinning
- 3)  $\pi$  –phase shift
- 4) Spin injection
- 5) Spin-accumulation
- 6) Andreev reflection

## **Proximity effect**



# 1) Influence of magnetism on supercond.

Intermixing  $\Rightarrow$  effective exchange field

 $H_{effect} = H_{ex} [d_F/(d_s+d_F)], T_c oscillation$ 



## 2) Influence of supercond. on magnetism

Intermixing  $\Rightarrow$  reconstruction of magnetic order

 $T_{curie}$  oscillation

## Vortex pining by domain wall



Attractive force by opposite directional magnetic-lines t

## **Experimental set-up (I)**





RF sputter system (Millton CVT, 13.6 MHz) Base pressure 10<sup>-8</sup> torr four guns Substrate temp. 1000 °C



- Step 1 Pre-heating  $La_2O_3$ : 900°C/3h.
- Step 2 Mix La<sub>2</sub>O<sub>3</sub>, SrCO<sub>3</sub>, MnCO<sub>3</sub>
- Step 3 Reaction: 1200°C/24 h
- Step 4 Pellet :d = 5 cm, Thick =1 cm, 3 tons/  $cm^{-2}$
- **Step 5** Anneal: 1400°C /16 h



Reactive co-sputtering process

<ul> <li>Substrate ⇒</li> </ul>	Si (100) , LaAlO <sub>3</sub> (100)	
• Target ⇒	YBCO, LSMO	
• RF power ⇒	80 Watt	
<ul> <li>Base pressure ⇒</li> </ul>	3 × 10 <sup>-7</sup> torr	
• Mixed gas $\Rightarrow$	Ar:O <sub>2</sub> =98:2	
Sputtering pressure	70 mtorr	
• Base temperature $\Rightarrow$	Room temperature	
• pre-sputtering $\Rightarrow$	3 minutes	
• Working distance $\Rightarrow$	10 cm	
Annealing tempert.	800 – 920 °C (700 °C)	
•Annealing time $\Rightarrow$	1 hrs	

#### **Post-annealing conditions**





## Experimental set-up (I)



#### • X-Ray Powder Diffractometer

(Japan MAC Sience, model MXP18)

#### • **AFM** (Solver P47)

#### Physical Property Measur. System

(Quantum design) 7 Tesla, 1.4 – 400 K Resisitivity, I-V curve AC/DC susceptibility





#### Structures of LSMO layer



#### AFM - granular





#### Magnetization for LSMO

#### H = 500 Gauss ZFC(black line); FC (red line)









H(Oe)

- For t<sub>LSMO</sub> < 50 nm Ferromagnetic insulator
- For  $t_{LSMO} \ge 50 \text{ nm}$   $T_{M-I} = 360 \text{ K}$ Ferromagnetic metal MR = -6.81%(at room temperature)

## Morphology of YBCO/LSMO (t)







Pure YBCO



Y/L(30nm)



Y/L(50nm)

## Resistivity for YBCO(150nm)/LSMO(t)





## Ground state of high-T<sub>c</sub> superconductor is an insulator ?



Solid lines: without field Open symbols: at 50 tesla



Vanacken et al., PRB 64 (2001)

#### Thermoelectric power

Obertelli et al., PBR 46 (1992) Our data  $T_c / T_c^{max}$ 0 0.5 0.5 0 28 1 L\_L 10 ۰ 2201 TI 🔺 ĕ 24 1212 TI • 2212 Bi 🔳 5 123 Y 🖕 100 2223 Tl + 20 S (290K) (µV/K)  $S(\mu V/K)$ 16 -5 ---YBCO 10 12 ĥ 0 1212 TI **→**t=30m -10 O. 2212 Bi -->--t**=50**m 8 0 123 Y  $^{\circ}$ LSCO x Ŷ٦ 120 160 200 280 240 -15 1+ 0.1 0.2 0 Temperature(K) Hole concentration

S (290K) (µV/K)

0.09 < n[Y/L(10-50 nm)] < 0.1 (YBCO)

### R-H curves at mixed state (50K) for Y/L(t) bilayers





#### Summary of MR in YBCO/LSMO(t) bilayers







#### I-V Characteristic (2 K) 09 **5**T 40mm 0.04 **4**T **Q6 Y/L(t)** YBCO 3Г 10mm 0.02 03 2Г 20m V (volt.) 1Т 0Т 30m V (volt) 0.00 00 YBCO -03 -0.02 -0.6 -0.04 -09 -5 -4 -3 -2 5 6 -6 -1 0 1 2 3 4 -2 -4 0 2 4 I(mA) **I (mA)**

 $I_c$  is defined as the current value where V = 1 µvolt.



## Magnetic dependent critical current density

 $J_{c} = I_{c}/cross-section$ Bean:  $\alpha = Bj_{c}$ K-A:  $\alpha = j_{c}(B+B_{o})$ 





## Hysteresis in V- I Characteristic





 Observing anti-clockwise hysteresis in YBCO/LSMO bilayers VOLUME 52, NUMBER 1

#### Flux-flow fingerprint of disorder: Melting versus tearing of a flux-line lattice

S. Bhattacharya and Mark J. Higgins NEC Research Institute, 4 Independence Way, Princeton, New Jersey 08540 (Received 25 April 1994)

- 1. Fingerprint of dynamics generated disorder via interaction between flux-line lattice & pinning centers.
- 2. A "tearing" of a soft lattice in a narrow regime of (H, T).
- 3. A first order depinning transition.



#### Equilibration and Dynamic Phase Transitions of a Driven Vortex Lattice

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Department of Physics and Astronomy, Rutgers University, Piscataway, New Jersey 08855

P. Shuk and M. Greenblatt Department of Chemistry, Rutgers University, Piscataway, New Jersey 08855 (Received 31 January 2000)



 $2H - NbSe_2$  at 4. 7 K, 1 Tesla T<sub>c</sub> = 7.1 K, H<sub>c2</sub> ~ 2.3 T

Only fast rate I-sweep produces Hysteresis (S =  $2 \times 10^2$  A/s)

When I increases, the flux-line lattice transits from a metastable to a stable state, followed by a dynamic crystallization transition at high currents. PHYSICAL REVIEW B 66, 144510 (2002)

#### History effect in inhomogeneous superconductors

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Ag-Bi2223 tape at 77 K; fast sweep
 Considering flux creep and inhomogenous Flux pinning;
 Clockwise hysteresis.







## **Conclusion**

- Suppression of T<sub>c</sub> in YBCO/LSMO(t) bilayer is observed at t = 50 nm, which should be originate from intrinsic proximity effect.
- Reversal of the sign of MR ratio in 50-nm YBCO/LSMO bilayer indicates the competition between superconductivity and ferromagnetism.
- We have observed magnetic pinning effect and hysteresis in V-I curves of YBCO/LSMO bilayers.